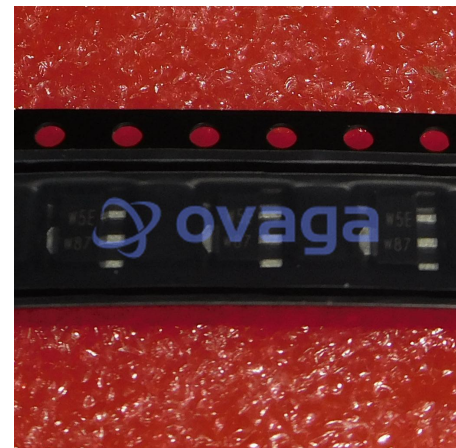


60 V, 4.7 A NPN low VCEsat (BISS) transistor

Manufacturers	NXP Semiconductor
Package/Case	SOT-89
Product Type	Discrete Semiconductors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for PBSS304NX or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

PBSS304NX is a type of NPN/PNP bipolar transistor in a SOT666 package. It is a high-performance switching transistor with low forward voltage drop and low leakage current.

Features

Collector-emitter voltage (VCEO) of 30 V

Collector current (IC) of 1 A

Low forward voltage drop (VF) of 0.25 V at 1 A

Low leakage current (ICES) of 2 nA at 25°C

Application

Power management in mobile devices

DC-DC converters

Load switches

Power drivers



Related Products



[PMPB10XNE](#)

NXP Semiconductor



[PBSS304PX](#)

NXP Semiconductor
SOT-89



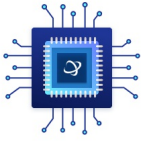
[PBSS4250X](#)

NXP Semiconductor
SOT89



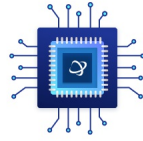
[PBSS5350SS](#)

NXP Semiconductor
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[PBSS9110T](#)

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[PBHV9115T](#)

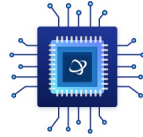
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